Docket No. AMENDMENT TRANSMITTAL LETTER T2171.0196 Application No. Filing Date Examiner Art Unit 09/873,580 June 4, 2001 F. Toledo 2823 Applicant(s): Harumitsu Fujita et al. Invention: MULTI-VOLTAGE LEVEL SEMICONDUCTOR DEVICE AND ITS MANUFACTURE TO THE COMMISSIONER FOR PATENTS Transmitted herewith is an amendment in the above-identified application. The fee has been calculated and is transmitted as shown below. **CLAIMS AS AMENDED** Claims Highest Remaining Number Number Previously Extra Claims After Amendment Present Paid Rate **Total Claims** 10 = Х Independent 2 = Х Claims Multiple Dependent Claims (check if applicable) Other fee (please specify):

| TOTAL ADDITIONAL FEE FOR THIS AMENL | JMENT: |
|--|--------------------------------------|
| x Large Entity | Small Entity |
| No additional fee is required for this amend | ment. |
| Please charge Deposit Account No. A duplicate copy of this sheet is enclosed. | in the amount of \$ |
| A check in the amount of \$ | to cover the filing fee is enclosed. |
| The Commissioner is hereby authorized to cas described below. A duplicate copy of this | • |
| x Credit any overpayment. | |
| X Charge any additional filing or application p | Dated: November 4, 2002 |
| Michael J. Scheer | 13131. |

Attorney Reg. No. 34,425

DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP

1177 Avenue of the Americas

41st Floor

New York, New York 10036-2714

(212) 896-5486

48493 v1; 11F101!.DOC 48493 v1; 11F101!.DOC

Approved for use through 10/31/2002. OMB 0651-0032
U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE
Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number.

| | DANOMITTAL | | | | | | Com | plete if Known | | |
|--|---|-----------------|------------|----------------------|--------------|---------------|-------------------------|--|---------------|--|
| | FEE TRANSMITTAL | | | Applie | cation | Numb | er | 09/873,580 | | |
| fo Patent fee | r FY 2002 | | | Filing | Date | | | June 4, 2001 | | |
| Patent fee | Patent fees are subject to annual revision. | | | First Named Inventor | | | ntor | Harumitsu Fujita et al. | | |
| Applicant claims TOTAL AMOUNT OF METHOD OF P | Sure subject to annual revision. | | -[| Exam | iner N | ame | | F. Toledo | | |
| Applicant claims | small entity status. See 37 CFR 1 | .27 | Γ | Group | Art U | nit | | 2823 | | |
| TOTAL AMOUNT OF | PAYMENT (\$) 400.0 | 00 | 寸 | | | cket No | | T2171.0196 | | |
| METHOD OF P | AYMENT (check all that apply) | Ť | | , thorr | <u> </u> | | | LATION (continued) | | |
| Check X Credit | Money | | | DDIT | 01/41 | | | EATION (continued) | | |
| Card Card | Order Other N | lone 3 | 5. A | אווטט | UNAL | FEES | | | | |
| Deposit Account | | - 1. | | | | | | | | |
| Deposit Account | 04-1073 | | arge ee | Entity Fee | Small Fee | Entity Fee | - | | | |
| Number | 04-1070 | C | ode | | Code | (\$) | | Fee Description | Fee Paid | |
| Deposit Dickste | in Shapiro Morin & | 1 | 105 | 130 | 205 | 65 | Surcharge | e – late filing fee or oath | | |
| Name | Oshinsky LLP | 1 | 127 | 50 | 227 | 25 | | e – late provisional filing fee or cover | | |
| l [57] | eby authorized to: (check all that appl | ^{y)} | | | | | sheet. | | | |
| X Charge fee(s) indicated | | ents 1 | 139 | 130 | 139 | 130 | Non-Engli | sh specification | | |
| application | fee(s) during the pendency of this | 1 | 147 | 2,520 | 147 | 2,520 | _ | request for ex parte reexamination | | |
| Charge fee(s) indicated | below, except for the filing fee | 1 | 12 | 920* | 112 | 920* | Requestin Examiner | g publication of SIR prior to action | | |
| to the above-identified dep | osit account. | 1 | 13 | 1,840* | 113 | 1,840* | Requestin | g publication of SIR after | | |
| FEE | CALCULATION | \dashv $_{1}$ | 15 | 110 | 215 | 55 | Examiner Extension | for reply within first month | | |
| 1. BASIC FILING FEE | | _ 1 | 16 | 400 | 216 | 200 | Extension | for reply within second month | 400.00 | |
| Large Entity Small Entit | `` | 1 | 17 | 920 | 217 | 460 | Extension | for reply within third month | | |
| Fee Fee Fee Fee Code (\$) | Fee Description | id 1 | 18 | 1,440 | 218 | 720 | Extension | for reply within fourth month | | |
| 101 740 201 370 | | | 28 | 1,960 | 228 | 980 | Extension | for reply within fifth month | | |
| 106 330 206 165 | | II | 19 | 320 | 219 | 160 | Notice of A | • • | | |
| 107 510 207 255 | <u> </u> | 1 | 20 | 320 | 220 | 160 | | ief in support offan appeal | | |
| 108 740 208 370 114 160 214 80 | | —ı ı | 21 38 | 280 1,510 | 221 138 | 140 1,510 | • | or oral hearing | | |
| | | | 40 | 110 | 240 | 55 | | institute a public use proceeding revive – unavoidable | | |
| s | UBTOTAL (1) (\$) 0.00 | | | 1,280 | 241 | 640 | | revive – unavoidable revive – unintentional | | |
| 2. EXTRA CLAIM FEI | ES FOR UTILITY AND REISSU | UE 1 | 42 | 1,280 | 242 | 640 | Utility issu | e fee (or reissue) | řň | |
| ł | Extra Fee from Fee Pa | aid 1 | 43 | 460 | 243 | 230 | Design iss | ue fee | C | |
| Total Claims 10 -31** | | 1 | 44 | 620 | 244 | 310 | Plant issue | e fee | 11 | |
| Independent 2 -3** | = x = | Ī 1 | 22 | 130 | 122 | 130 | Petitions to | the Commissioner | -< | |
| Multiple Dependent | = ===================================== | 7 1 | 23 | 50 | 123 | 50 | Processing | g fee under 37 CFR 1.17(g) | | |
| Large Entity Small Entity | · | _ 1 | 26 | 180 | 126 | 180 | Submissio | n of Information Disclosure Stmt | | |
| Fee Fee Fee Fee Code (\$) | Fee Description | 5 | 81 | 40 | 581 | 40 | | each patent assignment per imes number of properties) | | |
| 103 18 203 9 | Claims in excess of 20 | 1 | 46 | 740 | 246 | 370 | Filing a su | bmission after final rejection | | |
| 102 84 202 42 | Independent claims in excess of 3 | 1 | 40 | 740 | 240 | | (37 CFR 1 For each a | .129(a)) additional invention to be | | |
| # 404 000 L 004 110 | 44 141.4 4 4 4 4 1 1 1 1 1 1 1 1 1 1 | . 1 | дU | /40 1 | 2AU | 3 (1) | | | | |

| SUBMITTED BY | | Complete | (if applicable) |
|-------------------------------------|--|-----------|------------------|
| Name (Print/Type) Michael J. Scheer | Registration No. (Altorney/Agent) 34,425 | Telephone | (212) 835-1400 |
| Signature Wichae | J. Johnson | Date | November 4, 2002 |

149

179

169

740 249

740

900 169

*Reduced by Basic Filing Fee Paid

Other fee (specify)

900

Request for Continued Examination (RCE)

SUBTOTAL (3) (\$)

400.00

Request for expedited examination of a design application

104

109

110

280

18

204

209

210

140 Multiple dependent claim, if not paid

** Reissue independent claims

and over original patent

** Reissue claims in excess of 20

over original patent

SUBTOTAL (2) (\$)

**or number previously paid, if greater; For Reissues, see above



Docket No.: T2171.0196

(PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Harumitsu Fujita

Application No.: 09/873,580

Filed: June 4, 2001

For: MULTI-VOLTAGE LEVEL

SEMICONDUCTOR DEVICE AND ITS

MANUFACTURE

Group Art Unit: 2823

Examiner: F. Toledo

J. Micm 11/12/02

CEIVED V-7 2002

AMENDMENT

Box Non-Fee Amendment

Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Office Action mailed June 5, 2002, please amend the above-identified U.S. patent application as follows:

In the Claims:

Cancel claims 1,2,5 and 6.

(New) A method of manufacturing a semiconductor device comprising at least first and second MOS transistors, said method comprising:

providing a semiconductor substrate having at least first and second active regions of a first conductivity type;

forming a gate oxide layer having a first thickness onto at least said first and second active regions;

forming an electrode layer onto said gate oxide layer;

48483 v1; 11#R01!.DOC